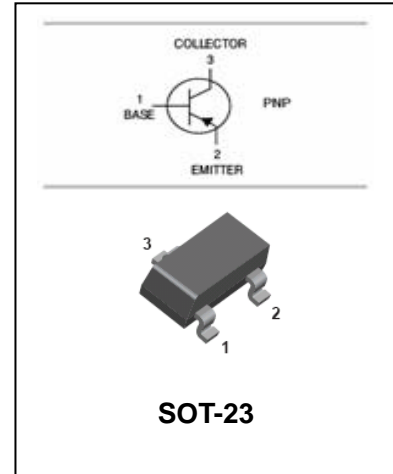


High Voltage Fast Switching PNP Power Transistor

3CD14001

FEATURES

- High speed switching.
- Small flat package.



APPLICATIONS

- High voltage switch mode application.

ORDERING INFORMATION

Type No.	Marking	Package Code
3CD14001	14001	SOT-23

MAXIMUM RATING @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	-400	V
V _{CEO}	Collector-Emitter Voltage	-400	V
V _{EBO}	Emitter-Base Voltage	-7	V
I _C	Collector Current -Continuous	-0.2	A
P _C	Collector Dissipation	350	mW
T _j , T _{stg}	Junction and Storage Temperature	-55 to +150	°C



High Voltage Fast Switching PNP Power Transistor

3CD14001

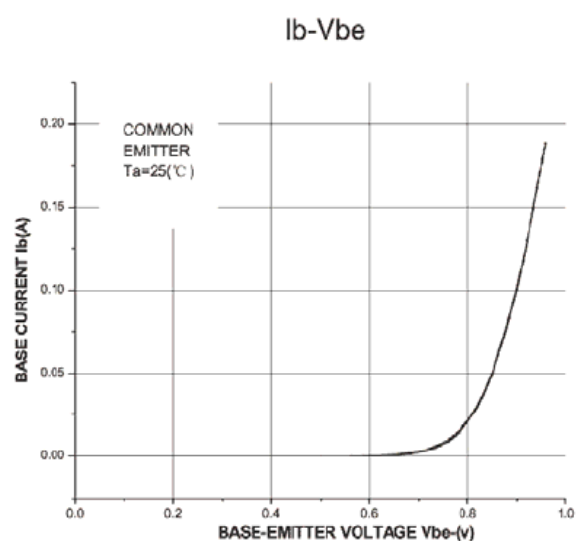
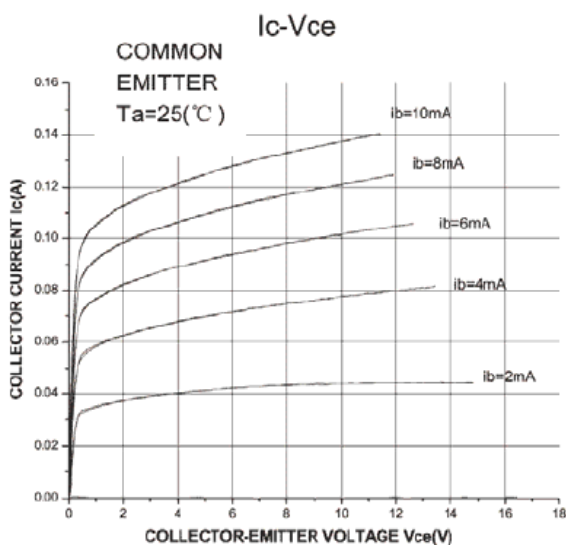
ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -100\mu A, I_E = 0$	-400			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -1mA, I_B = 0$	-400			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -100\mu A, I_C = 0$	-7			V
Collector cut-off current	I_{CBO}	$V_{CB} = -400V, I_E = 0$			-100	μA
Collector cut-off current	I_{CEO}	$V_{CE} = -400V, I_B = 0$			-200	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -7V, I_C = 0$			-100	μA
DC current gain	h_{FE}	$V_{CE} = -20V, I_C = -20mA$	10		40	
		$V_{CE} = -10V, I_C = -0.25A$	5			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -50mA, I_B = -10mA$			-0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = -50mA, I_B = -10mA$			-1.2	V
Transition frequency	f_T	$V_{CE} = -20V, I_C = -20mA, f = 1MHz$	8			MHz
Fall time	t_f	$I_C = 50mA, I_{B1} = I_{B2} = 5mA, V_{CC} = 45V$			0.3	μS
Storage time	t_s				1.5	μS

CLASSIFICATION OF $h_{FE(1)}$

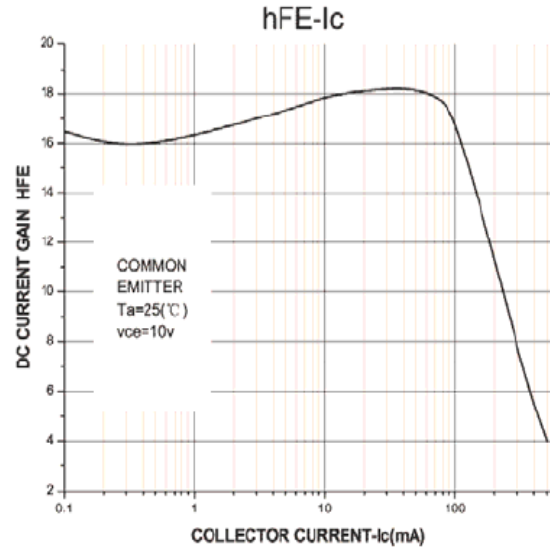
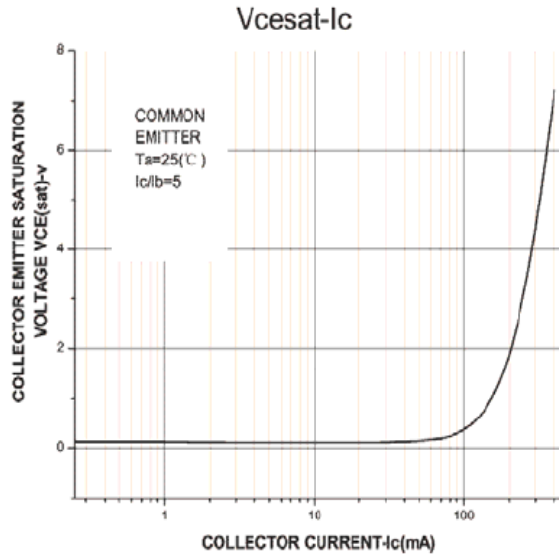
Range	10-15	15-20	20-25	25-30	30-35	35-40

TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified



High Voltage Fast Switching PNP Power Transistor

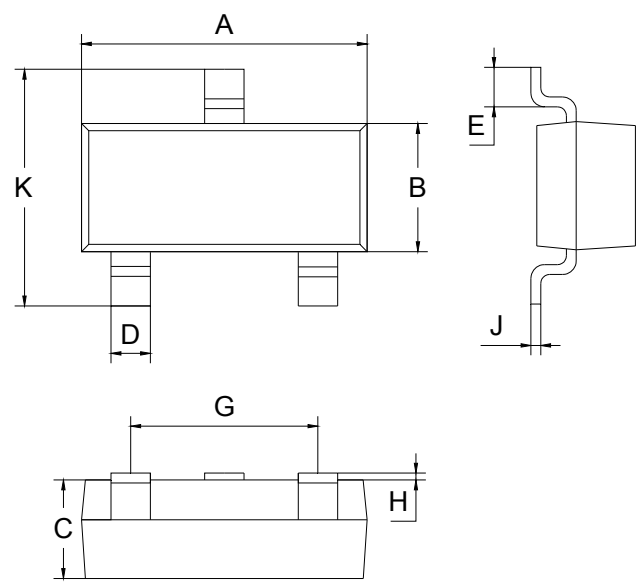
3CD14001



PACKAGE OUTLINE

Plastic surface mounted package

SOT-23



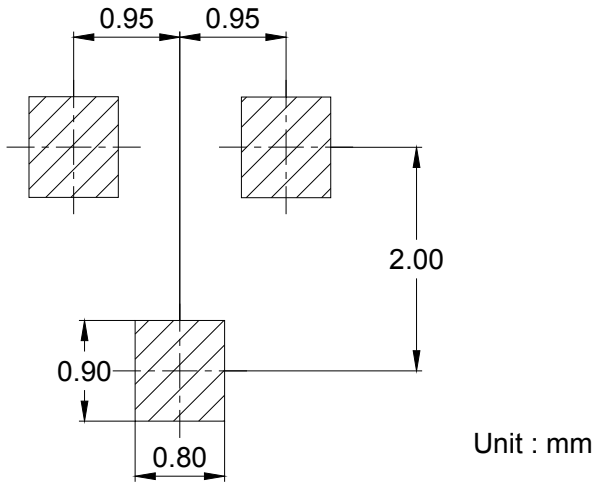
SOT-23		
Dim	Min	Max
A	2.70	3.10
B	1.10	1.50
C	1.0 Typical	
D	0.4 Typical	
E	0.35	0.48
G	1.80	2.00
H	0.02	0.1
J	0.1 Typical	
K	2.20	2.60
All Dimensions in mm		



High Voltage Fast Switching PNP Power Transistor

3CD14001

SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
3CD14001	SOT-23	3000/Tape&Reel